

1. DESCRIPTION

1.1 Features

- Current transfer ratio (CTR) : MIN. 20% at $I_F = \pm 1$ mA, $V_{CE} = 5$ V)
- High input-output isolation voltage. (V_{iso}=3,750Vrms)
- Employs double transfer mold technology
- Safety approval:

UL 1577

VDE DIN EN60747-5-5 (VDE 0884-5),

CSA CA5A

FIMKO

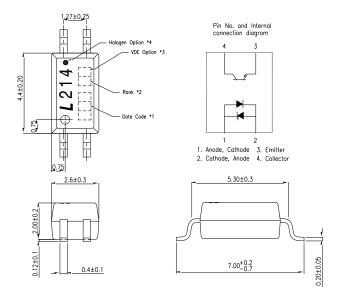
- RoHS Compliance: All materials be used in device are followed EU RoHS directive (No.2002/95/EC).
- ESD pass HBM 6000V/MM2000V
- MSL class1

1.2 Applications

- Hybrid substrates that require high density mounting.
- Programmable controllers
- System appliances, measuring instruments

2. PACKAGE DIMENSIONS

2.1 LTV-214-G

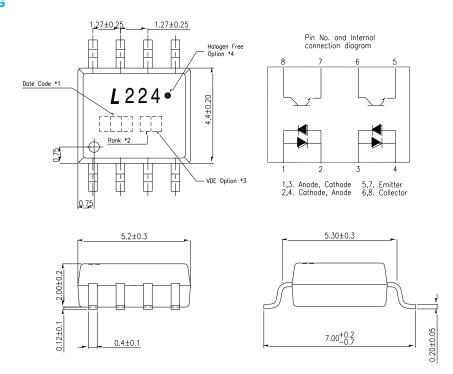


Notes:

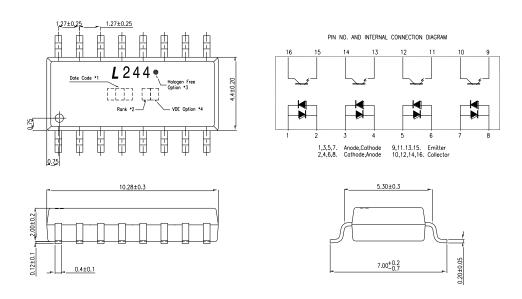
- 1. 3-digit date code.
- 2. Rank shall be or shall not be marked.
- 3. VDE mark only appears on devices ordered "V" option.
- 4. "●" for halogen free option.



2.2 LTV-224-G



2.3 LTV-244-G



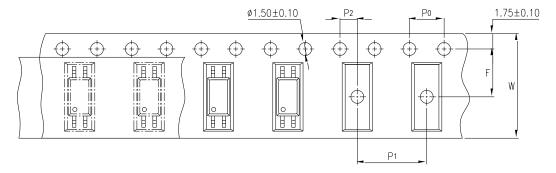
Notes:

- 1. 3-digit date code.
- 2. Rank shall be or shall not be marked.
- 3. VDE mark only appears on devices ordered "V" option.
- 4. "●" for halogen free option.

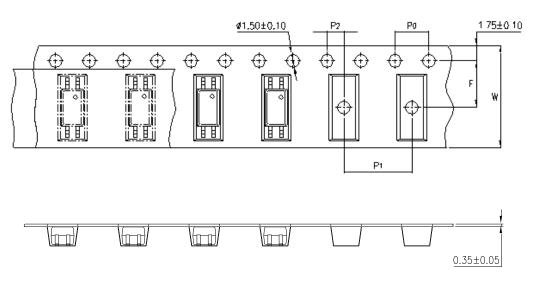


3. TAPING DIMENSIONS

3.1 P/N: LTV-214-G



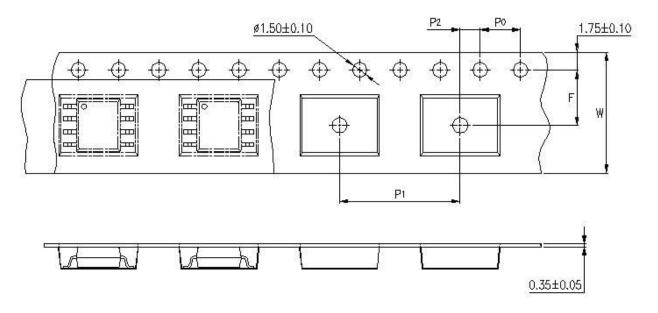
3.2 P/N: LTV-214-TP1-G



Description	Symbol	Dimension in mm (inch)
Tape wide	W	12±0.3 (0.47)
Pitch of sprocket holes	P ₀	4±0.1 (0.15)
Distance of compartment	F	5.5±0.1 (0.217)
Distance of compartment	P_2	2±0.1 (0.079)
Distance of compartment to compartment	P ₁	8±0.1 (0.315)



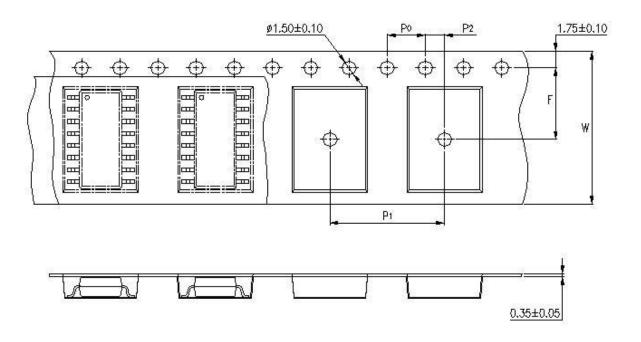
3.3 P/N:LTV-224-G



Description	Symbol	Dimension in mm (inch)
Tape wide	W	12±0.3 (0.47)
Pitch of sprocket holes	P_0	4±0.1 (0.15)
Distance of compartment	F	5.5±0.1 (0.217)
Distance of compartment	P_2	2±0.1 (0.079)
Distance of compartment to compartment	P ₁	8±0.1 (0.315)



3.4 P/N: LTV-244-G



Description	Symbol	Dimension in mm (inch)
Tape wide	W	16±0.3 (0.47)
Pitch of sprocket holes	P ₀	4±0.1 (0.15)
Distance of compartment	F	7.5±0.1 (0.217)
Distance of compartment	P_2	2±0.1 (0.079)
Distance of compartment to compartment	P ₁	12±0.1 (0.315)

3.5 Quantities per Reel

Package Type	LTV-214-G	LTV-224-G	LTV-244-G
Quantities (pcs)	3000	2000	2000



4. RATING AND CHARACTERISTICS

4.1 Absolute Maximum Ratings at Ta=25°C

			Rating			
	Parameter	Symbol	214	224	244	Unit
	Forward Current	I _F		50		mA
lanut.	Reverse Voltage	V_R	6		V	
Input	Power Dissipation	Р		65		mW
	Pulse Forward Current	I _{FSM}	1		А	
	Collector - Emitter Voltage	V_{CEO}	80		V	
Outrot	Emitter - Collector Voltage	V _{ECO}		7		V
Output	Collector Current	I _C	50		mA	
	Collector Power Dissipation	Pc	150	0	100	mW
	Total Power Dissipation	P _{tot}	200	0	170	mW
1.	Isolation Voltage	V _{iso}		3750		V_{rms}
	Operating Temperature	T_{opr}	-55	5 ~ +11	0	°C
	Storage Temperature	T_{stg}	-55	5 ~ +15	60	°C
	Soldering Temperature	T _{sol}	26	60(10s)	°C

1. AC For 1 Minute, R.H. = $40 \sim 60\%$

Isolation voltage shall be measured using the following method.

- (1) Short between anode and cathode on the primary side and between collector and emitter on the secondary side.
- (2) The isolation voltage tester with zero-cross circuit shall be used.
- (3) The waveform of applied voltage shall be a sine wave.



4.2 ELECTRICAL OPTICAL CHARACTERISTICS at Ta=25°C

Parameter		Symbol	Min.	Тур.	Max.	Unit	Test Condition
Input	Forward Voltage	V _F	_	1.2	1.4	V	I _F =±20mA
mput	Terminal Capacitance	Ct	_	60	_	pF	V=0, f=1KHz
	Collector Dark Current	I _{CEO}	_	_	100	nA	V _{CE} =20V, I _F =0
Output	Collector-Emitter Breakdown Voltage	BV _{CEO}	80	_	_	V	I _C =0.1mA, I _F =0
	Emitter-Collector Breakdown Voltage	BV _{ECO}	7	_	_	V	I _E =10μΑ, I _F =0
	Collector-Emitter Saturation Voltage	$V_{\text{CE(sat)}}$	_	_	0.4	V	I _F ±8mA, I _C =2.4mA
TRANSFER CHARACTERISTICS	Isolation Resistance	R _{iso}	5×10 ¹⁰	1×10 ¹¹	_	Ω	DC500V, 40 ~ 60% R.H.
	Floating Capacitance	Cf	_	0.8	1	pF	V=0, f=1MHz
	Response Time (Rise)	tr	_	3	18	μS	V _{CE} =10V, I _C =±2mA
	Response Time (Fall)	tf	_	4	18	μS	R _L =100Ω, f=100Hz



5. RANK TABLE OF CURRENT TRANSFER RATIO CTR

Model No.	CTR Rank	Min	Max	Condition	
	0	20	400		
	А	50	250	I _F =±1mA, V _{CE} =5V, Ta=25°C	
LTV-214-G	AK	100	200	1F-111111, VCE-5V, 14-25 C	
	В	100	400		
	GR	100	300	I _F =±5mA, V _{CE} =5V, Ta=25°C	
	0	20	400	I _F =±1mA, V _{CE} =5V, Ta=25°C	
LTV-224-G LTV-244-G	A5	100	300	1F-±1111/1, V _{CE} -OV, 1a-20 O	
	GB	100	400	I _F =±5mA, V _{CE} =5V, Ta=25°C	

$$CTR = \frac{I_C}{I_F} \times 100\%$$



6. CHARACTERISTICS CURVES

Figure 1. Collector Power Dissipation vs. Ambient Temperature

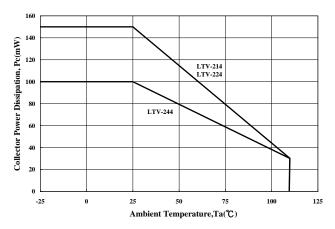


Figure 2. Forward Current vs. Ambient Temperature

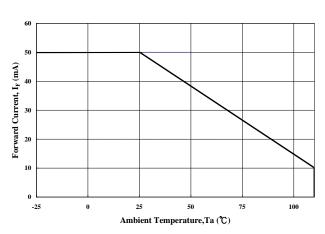


Figure 3. Forward Current vs. Forward Voltage

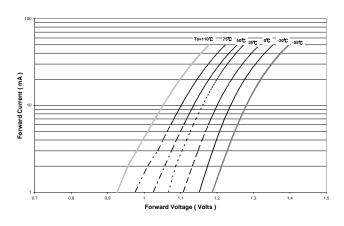


Figure 4. Forward Voltage Temperature Coefficient vs.

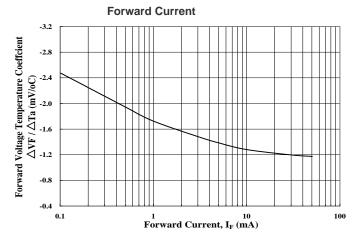


Figure 5. Pulse Forward Current vs. Duty Cycle Ratio

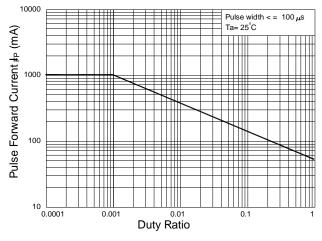


Figure 6. Pulse Forward Current vs. Pulse Forward

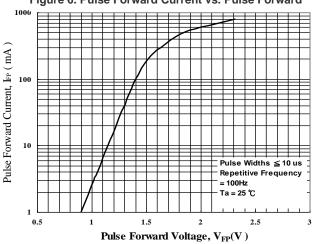




Figure 7. Collector-Emitter Saturation Voltage vs. Forward

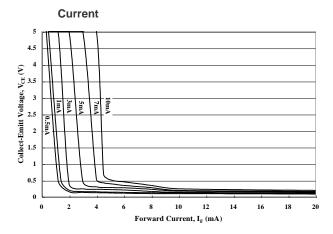


Figure 8. Collector Current vs. Collector-Emitter

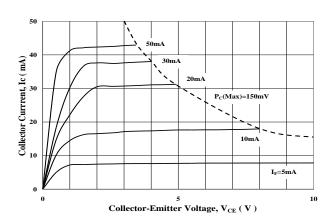


Figure 9. Collector Current vs. Small Collector-Emitter

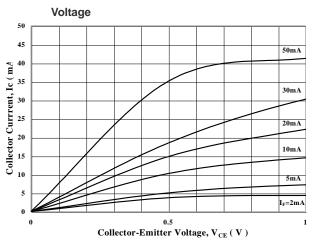


Figure 10. Normalzied CTR vs. Forward Current

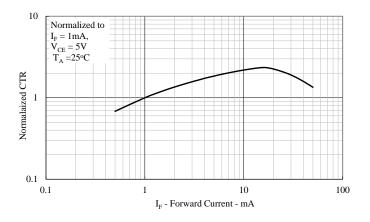


Figure 11. Collector Dark Current vs. Ambient Temperature

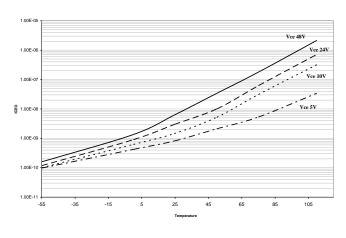


Figure 12. Current Transfer Ratio vs. Forward

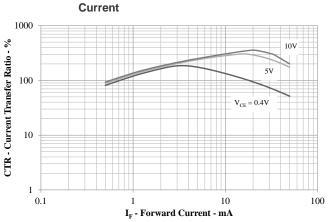




Figure 13. Collector-Emitter Saturation Voltage vs.

Ambient Temperature

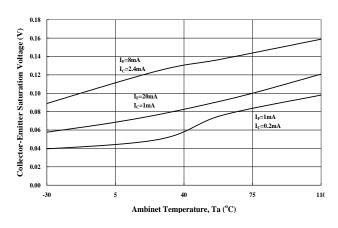


Figure 14. Collector Current vs. Ambient Temperature

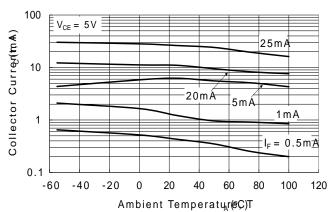


Figure 15. Switching Time vs. Load Resistance

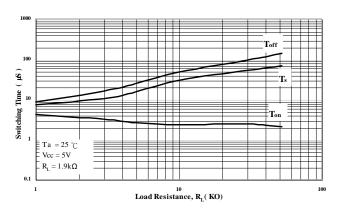


Figure 16. Switching Time vs. Ambient Temperature

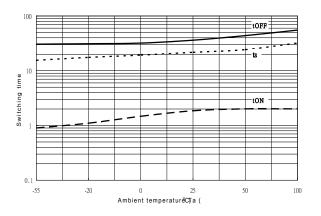
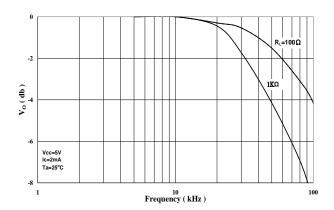
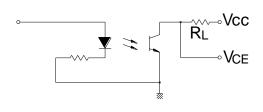


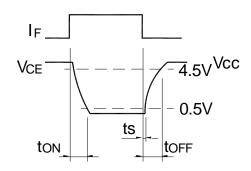
Figure 17. Frequency Response





7. SWITCHING TIME TEST CIRCUIT





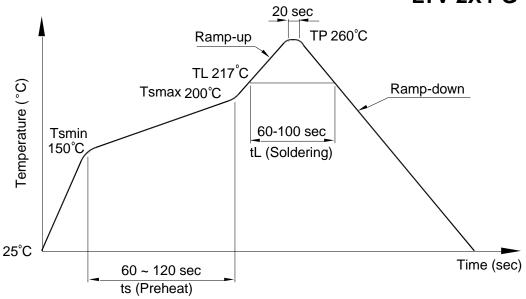
8. TEMPERATURE PROFILE OF SOLDERING

8.1 IR Reflow soldering (JEDEC-STD-020C compliant)

One time soldering reflow is recommended within the condition of temperature and time profile shown below. Do not solder more than three times.

Profile item	Conditions
Preheat	
- Temperature Min (T _{Smin})	150°C
- Temperature Max (T _{Smax})	200°C
- Time (min to max) (ts)	90±30 sec
Soldering zone	
- Temperature (T _L)	217°C
- Time (t _L)	60 ~ 100 sec
Peak Temperature (T _P)	260°C
Ramp-up rate	3°C / sec max.
Ramp-down rate	3~6°C / sec





8.2 Wave soldering (JEDEC22A111 compliant)

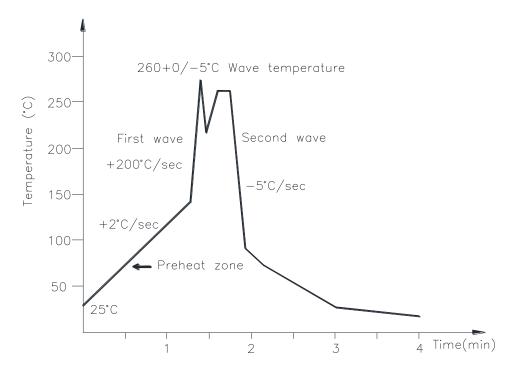
One time soldering is recommended within the condition of temperature.

Temperature: 260+0/-5°C

Time: 10 sec.

Preheat temperature:25 to 140°C

Preheat time: 30 to 80 sec.





8.3 Hand soldering by soldering iron

Allow single lead soldering in every single process. One time soldering is recommended.

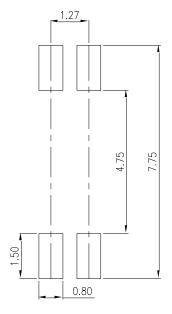
Temperature: 380+0/-5°C

Time: 3 sec max.

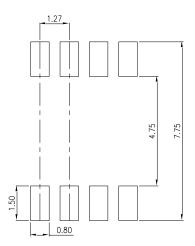
9. RRECOMMENDED FOOT PRINT PATTERNS (MOUNT PAD)

Unit: mm

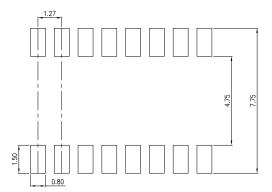
P/N: LTV-214



P/N: LTV-224



P/N: LTV-244







10. Notes:

- LiteOn is continually improving the quality, reliability, function or design and LiteOn reserves the right to make changes without further notices.
- The products shown in this publication are designed for the general use in electronic applications such as office automation equipment, communications devices, audio/visual equipment, electrical application and instrumentation.
- For equipment/devices where high reliability or safety is required, such as space applications, nuclear power control equipment, medical equipment, etc, please contact our sales representatives.
- When requiring a device for any "specific" application, please contact our sales in advice.
- If there are any questions about the contents of this publication, please contact us at your convenience.
- The contents described herein are subject to change without prior notice.
- Immerge unit's body in solder paste is not recommended.